



BDS-SMY Family Picosecond Diode Lasers

The BDS-SMY lasers close the wavelength gap in the spectrum of ps diode lasers in the 520 to 630 nm range. The lasers are based on the QLD series laser modules of QD Laser Inc., Japan. These modules contain an IR laser diode, an amplifier diode, and a frequency doubler. Combined with bh BDS laser series technology, the BDS-SMY lasers provide picosecond light pulses of short pulse width and narrow bandwidth at wavelengths of 532 nm, 561 nm, and 594 nm.

Small-size OEM Module, 40 x 40 x 120 mm³ or 40 x 70 x 120 mm³

Wavelengths 532 nm, 561 nm, 594 nm**

Free-beam or single-mode fibre output

Pulse width down to 50 ps

Pulse repetition rate 20/50* MHz

Internal clock or synchronisation to external clock source

CW-equivalent power 0.3 to 0.5 mW @ 50 MHz

Fast on / off / multiplexing capability

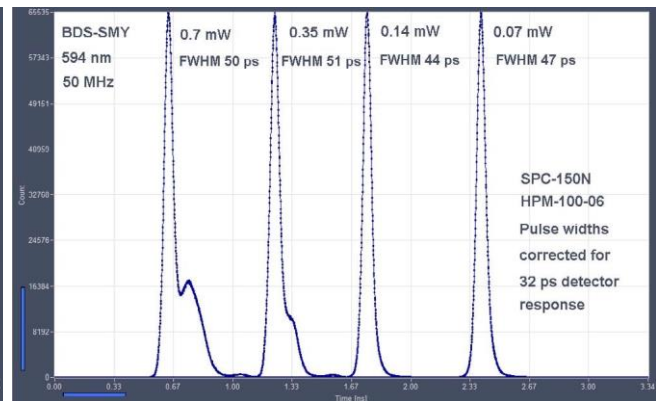
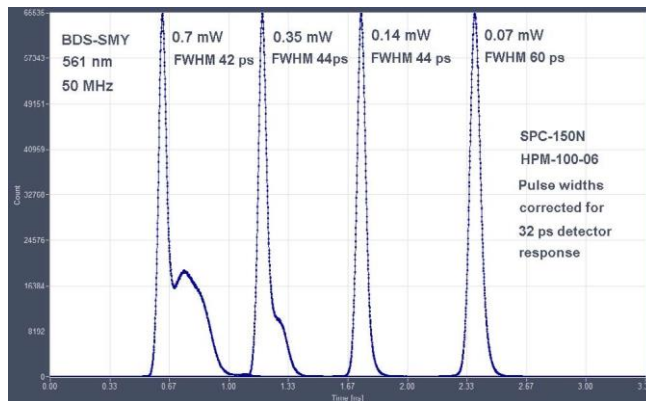
Internal power stabilisation loop

All electronics integrated

No external driver unit

Simple +12 V power supply

Compatible with all bh TCSPC devices



Pulse shapes and power levels may change due to development in laser diode technology. Coupling efficiency into single-mode fibres is 40 to 60 %.

* Laser power and power control is optimized for one frequency.

** Manufactured under license under German utility model #: DE202013006817.5

Designed and manufactured by



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BDS-SMY

Optical

Repetition Rate, switchable by TTL signal
 Wavelengths
 Pulse width (FWHM, at medium power)
 Power control range (power in free beam)
 Beam diameter, free beam
 Polarisation
 Coupling efficiency into single-mode fibre, typically

20 MHz and 50 MHz, other repetition rates on request
 532 nm, 561 nm, 594 nm
 40 to 80 ps
 typically 0 to 0.5 mW¹⁾
 1 mm x 2 mm
 horizontal
 up to 50 %

Trigger Output, to TCSPC Modules

Pulse Amplitude
 Pulse Width
 Output Impedance
 Connector
 Jitter between Trigger and Optical Pulse

-1.2 V (peak) into 50 Ω
 1 ns, see figure right
 50 Ω
 SMA
 < 10 ps

Synchronisation Input

Input amplitude
 Duty cycle
 Input frequency
 Connector
 Switch between internal clock and sync input

+3.3 to +5 V into 50 Ω
 10 to 30 %. DC equivalent must be < 2.5 V
 20 to 60 MHz¹⁾
 SMA
 automatic, by average voltage at trigger connector

Control Inputs

Laser ON/OFF
 Response of optical output to ON/OFF signal
 External Power Control
 Response time of optical output to power control
 F1: 50 MHz
 F2: 20 MHz

TTL / CMOS, 'low' means 'OFF', internal pull-up
 < 4 μ s for power 10 to 100 %, see figures right
 analog input, 0 to +10 V
 < 4 μ s for power 10 to 100 %, see figure right
 active H, internal pull-up resistor
 active H, internal pull-down resistor
 Laser runs at 50 MHz when 'Fx' inputs unconnected

Power Supply

Power Supply Voltage
 Power Supply Current at 12V

+9 V to +15 V
 200 mA to 500 mA²⁾

Mechanical Data

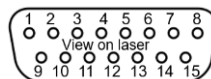
Dimensions (OEM)
 Dimensions (w/ cooling)
 Mounting holes
 Heat sink requirements

40 mm x 40 mm x 120 mm
 40 mm x 70 mm x 120 mm
 four holes for M3 screws
 < 2 °C / W³⁾

Connector Pin Assignment

Connector version
 Power supply +12V
 GND
 Power control voltage
 Laser ON/OFF (TTL/CMOS, active H)
 F2: 20 MHz (active H, int. pull-down resistor)
 F1: 50 MHz (active H, int. pull-up resistor)
 Do not connect:

Mini Sub-D 15 pin
 1, 2
 4, 5, and case
 8
 6
 3
 7
 9, 10, 11, 12, 13, 14, 15



Maximum Values

Power Supply Voltage
 Voltage at 'Laser ON/OFF' and 'Frequency' inputs
 Voltage at 'Laser Power' input
 Ambient Temperature

0 V to +15 V
 -2 V to +7 V
 -12 V to +12 V
 0 °C to +40 °C³⁾

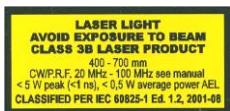
1) Laser power and power control is optimized for one frequency, only.

2) Depends on case temperature due to laser diode cooling. Cooling current changes with case temperature.

3) OEM version without active cooling must be mounted on heat sink. Case temperature must remain below 40 °C.

Related Products

BDS-MM picosecond diode lasers, BDS-SMN picosecond and CW diode lasers, 375, 405, 445, 473, 488, 515, 640, 685, 785, 1064 nm



Caution: Class 3B laser product. Avoid direct eye exposure. Light emitted by the device may be harmful to the human eye. Please obey laser safety rules when operating the devices.
Complies with US federal laser product performance standards.

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 高速分光測定装置、クライオスタット



Nd:YAGレーザー、Ti:Sレーザー
 OPOレーザー

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